

### FEATURES

- Rack mounted system
- Class AB linear GaAsFET design
- Instantaneous wide bandwidth
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



### ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	18.0 - 26.5 GHz	
Power Output CW	10 Watt Min	
Power Output @ P1dB	10 Watt Typ	Few frequency spots that could be marginal 10W
Power Gain	40 dB Min	
Power Gain Flatness	4.0 dB p-p Max	Constant input power
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	30dBm/Tone, Δ = 1MHz
Harmonics	-20 dBc Typ	At rated Pout
Spurious	60 dBc Min	Non-harmonics
Operating Voltage	100 - 240 VAC	
Power Consumption	220 Watt Max	
Max Input Power Protection	+3 dBm	10 Sec without damage
Load VSWR Protection	5 : 1	<1 minute at rated Pout

### ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensation

### MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 562 mm	2U
Weight	9 kg.	
RF Connectors In/Out	2.9 mm (K / air type) Female	Front Panel Standard
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	
<b>OPTIONAL:</b> Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485 Optional GPIB Interface	Remote Bluetooth application

### OUTLINE DRAWING

